

## UHF BAND POWER AMPLIFIER APPLICATIONS.

## FEATURES:

- Output Power :  $P_o=12W$ (Min.)  
( $f=470MHz$ ,  $V_{CC}=12.6V$ ,  $P_i=3W$ )
- 100% Tested for Load Mismatch Stress at All Phase Angles with 30:1 VSWR @  $V_{CC}=12.6V$ ,  $P_i=3W$ ,  $f=470MHz$

MAXIMUM RATINGS ( $T_a=25^\circ C$ )

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$V_{CBO}$	35	V
Collector-Emitter Voltage	$V_{CEO}$	17	V
Emitter-Base Voltage	$V_{EBO}$	3.5	V
Collector Current	$I_C$	2.8	A
Collector Power Dissipation ( $T_c=25^\circ C$ )	$P_C$	30	W
Junction Temperature	$T_j$	$175$	$^\circ C$
Storage Temperature Range	$T_{stg}$	$165 \sim 175$	$^\circ C$

Unit in mm

1. Emitter  
 2. Base  
 3. Emitter  
 4. Collector

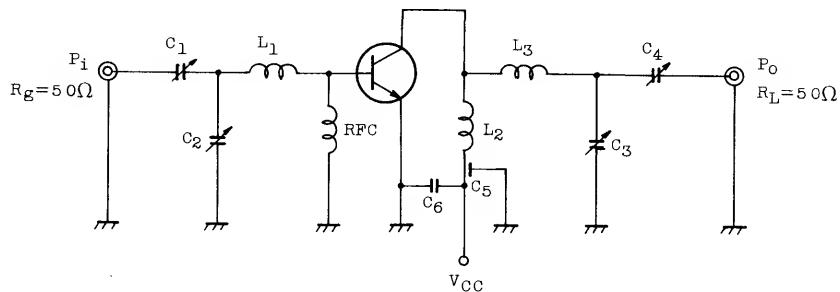
JEDEC		-
EIAJ		-
TOSHIBA		2-10H1A

Weight : 4g

ELECTRICAL CHARACTERISTICS ( $T_c=25^\circ C$ )

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB}=15V$ , $I_E=0$	-	-	1.5	mA
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=2mA$ , $I_E=0$	35	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=10mA$ , $I_B=0$	17	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=0.2mA$ , $I_C=0$	3.5	-	-	V
DC Current Gain	$h_{FE}$	$V_{CE}=5V$ , $I_C=1.5A$	10	-	-	-
Collector Output Capacitance	$C_{ob}$	$V_{CB}=10V$ , $I_E=0$ , $f=1MHz$	-	-	45	pF
Output Power	$P_o$	(Fig.)	12	-	-	W
Power Gain	$G_{pe}$	$V_{CC}=12.6V$ , $f=470MHz$ ,	7.7	-	-	dB
Collector Efficiency	$\eta_c$	$P_i=3W$	60	-	-	%
Series Equivalent Input Impedance	$Z_{IN}$	$V_{CC}=12.6V$ , $f=470MHz$ ,	-	$1.5+j1.3$	-	$\Omega$
Series Equivalent Output Impedance	$Z_{OUT}$	$P_o=12W$	-	$3.6-j1.8$	-	$\Omega$

Fig. f=470MHz P<sub>O</sub> TEST CIRCUIT



C<sub>1</sub>, C<sub>3</sub> : 1.5 ~ 5pF

C<sub>2</sub>, C<sub>1</sub> : 2 ~ 15pF

C<sub>5</sub> : 1000pF FEED THROUGH

C<sub>6</sub> : 0.01μF

L<sub>1</sub>, L<sub>3</sub> : 5mm×15mm COPPER PLATE

L<sub>2</sub> : φ1 SILVER PLATED COPPER WIRE, 10ID,  $\frac{1}{8}$ T

RFC : φ1 ENAMEL COATED COPPER WIRE, 3ID, 5T

